

## 6 Channel EMI Filter Array with ESD Protection

### Features

- Six channels of EMI filtering for data ports
- Pi-style EMI filters in a capacitor-resistor-capacitor (C-R-C) network
- Greater than 32dB attenuation at 1GHz
- $\pm 15\text{kV}$  ESD protection on each channel (IEC 61000-4-2 Level 4, contact discharge)
- $\pm 30\text{kV}$  ESD protection on each channel (HBM)
- Chip Scale Package features extremely low lead inductance for optimum filter and ESD performance
- 15-bump, 2.960mm X 1.330mm footprint Chip Scale Package (CSP)
- Lead-free version available

### Applications

- EMI filtering and ESD protection for both data and I/O ports
- Wireless Handsets
- Handheld PCs / PDAs
- MP3 Players
- Notebooks
- Desktop PCs

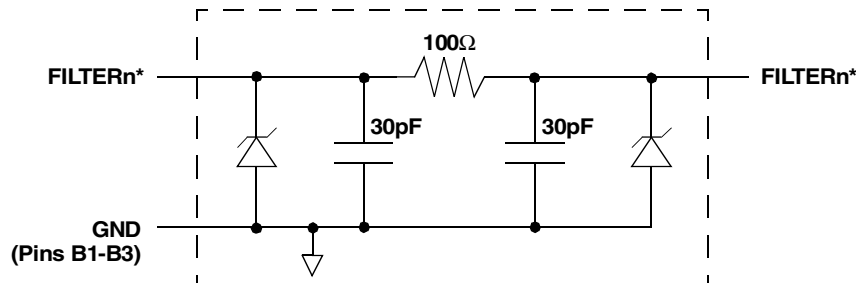
### Product Description

The CSPEMI306A is a six channel low-pass filter array that reduces EMI/RFI emissions while at the same time providing ESD protection. It is used on data ports on mobile devices. To reduce EMI/RFI emissions, the CSPEMI306A integrates a pi-style filter (C-R-C) for each of the 6 channels. Each high quality filter provides greater than 30dB attenuation in the 800-2700 MHz range. These pi-style filters also support bidirectional filtering, controlling EMI both to and from a data port connector.

In addition, the CSPEMI306A provides a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The input pins are designed and characterized to safely dissipate ESD strikes of 15kV, exceeding the maximum requirement of the IEC 61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the device provides protection for contact discharges to greater than 30kV.

The CSPEMI306A is particularly well suited for portable electronics (e.g., cellular telephones, PDAs, notebook computers) because of its small package footprint and low weight. The CSPEMI306A is available in a space-saving, low-profile Chip Scale Package with optional lead-free finishing.

### Electrical Schematic

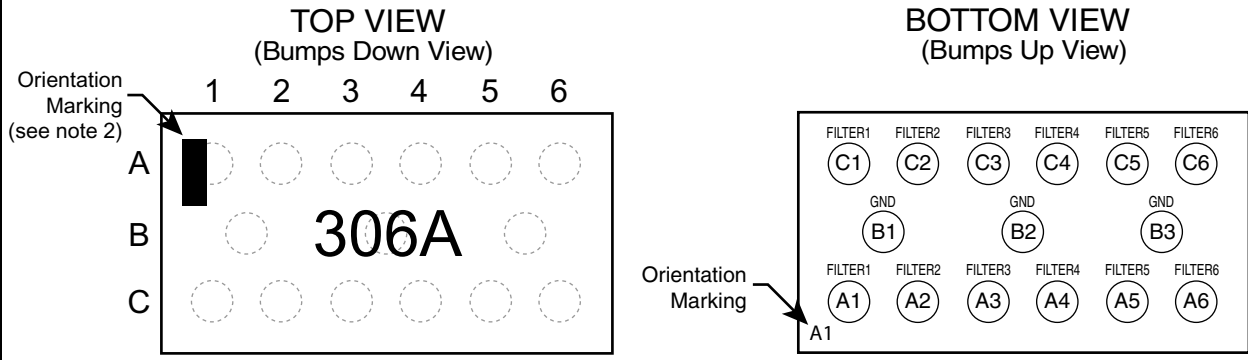


1 of 6 EMI/RFI + ESD Channels

\* See Package/Pinout Diagram for expanded pin information.



**PACKAGE / PINOUT DIAGRAMS**



CSPEMI306A  
CSP Package

Notes:

- 1) These drawings are not to scale.
- 2) Lead-free devices are specified by using a "+" character for the top side orientation mark.

**PIN DESCRIPTIONS**

PIN(s)	NAME	DESCRIPTION
A1	FILTER1	Filter Channel 1
A2	FILTER2	Filter Channel 2
A3	FILTER3	Filter Channel 3
A4	FILTER4	Filter Channel 4
A5	FILTER5	Filter Channel 5
A6	FILTER6	Filter Channel 6
B1-B3	GND	Device Ground
C1	FILTER1	Filter Channel 1
C2	FILTER2	Filter Channel 2
C3	FILTER3	Filter Channel 3
C4	FILTER4	Filter Channel 4
C5	FILTER5	Filter Channel 5
C6	FILTER6	Filter Channel 6

**Ordering Information**

**PART NUMBERING INFORMATION**

Bumps	Package	Standard Finish		Lead-free Finish <sup>2</sup>	
		Ordering Part Number <sup>1</sup>	Part Marking	Ordering Part Number <sup>1</sup>	Part Marking
15	CSP	CSPEMI306A	306A	CSPEMI306AG	306A

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

Note 2: Lead-free devices are specified by using a "+" character for the top side orientation mark.

## Specifications

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNITS
Storage Temperature Range	-65 to +150	°C
DC Power per Resistor	100	mW
DC Package Power Rating	600	mW

### STANDARD OPERATING CONDITIONS

PARAMETER	RATING	UNITS
Operating Temperature Range	-40 to +85	°C

### ELECTRICAL OPERATING CHARACTERISTICS<sup>1</sup>

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
R	Resistance		80	100	120	Ω
C	Capacitance	At 2.5V DC	24	30	36	pF
TCR	Temperature Coefficient of Resistance			1200		ppm/°C
TCC	Temperature Coefficient of Capacitance	At 2.5V DC		-300		ppm/°C
V <sub>DIODE</sub>	Diode Voltage (reverse bias)	I <sub>DIODE</sub> =10μA	5.5			V
I <sub>LEAK</sub>	Diode Leakage Current (reverse bias)	V <sub>DIODE</sub> =3.3V			100	nA
V <sub>SIG</sub>	Signal Voltage Positive Clamp Negative Clamp	I <sub>LOAD</sub> = 10mA	5.6 -0.4	6.8 -0.8	9.0 -1.5	V V
V <sub>ESD</sub>	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2 Level 4	Notes 2,4 and 5	±30 ±15			kV kV
V <sub>CL</sub>	Clamping Voltage during ESD Discharge MIL-STD-883 (Method 3015), 8kV Positive Transients Negative Transients	Notes 2,3,4 and 5		+10 -5		V V
f <sub>C</sub>	Cut-off frequency Z <sub>SOURCE</sub> = 50Ω, Z <sub>LOAD</sub> = 50Ω	R = 100Ω, C = 30pF		58		MHz

Note 1: T<sub>A</sub>=25°C unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: Clamping voltage is measured at the opposite side of the EMI filter to the ESD pin. For example, if ESD is applied to Pin A1, then clamping voltage is measured at Pin C1.

Note 4: Unused pins are left open

Note 5: These parameters are guaranteed by design and characterization.



### Performance Information

Typical Filter Performance ( $T_A=25^\circ\text{C}$ , DC Bias=0V, 50 Ohm Environment)

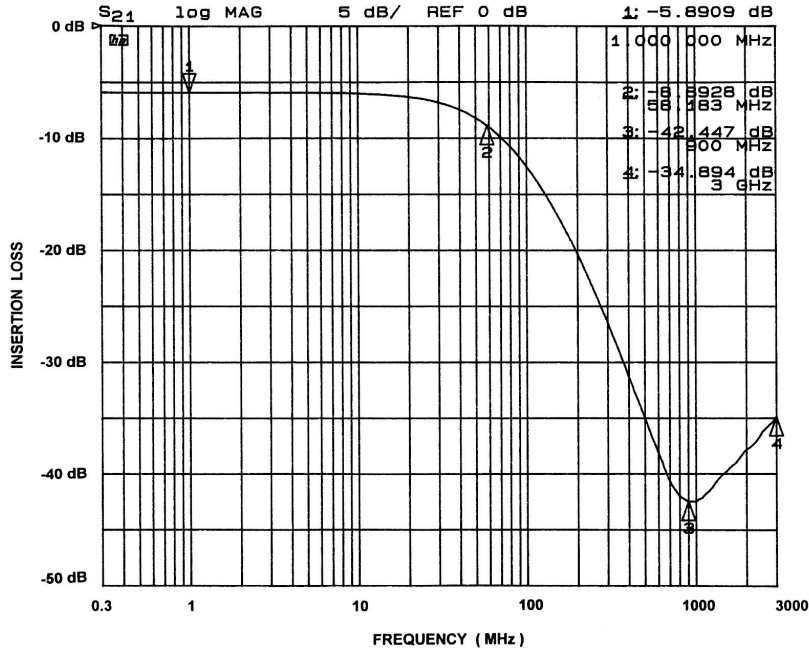


Figure 1. Insertion Loss VS. Frequency (A1-C1 to GND B2)

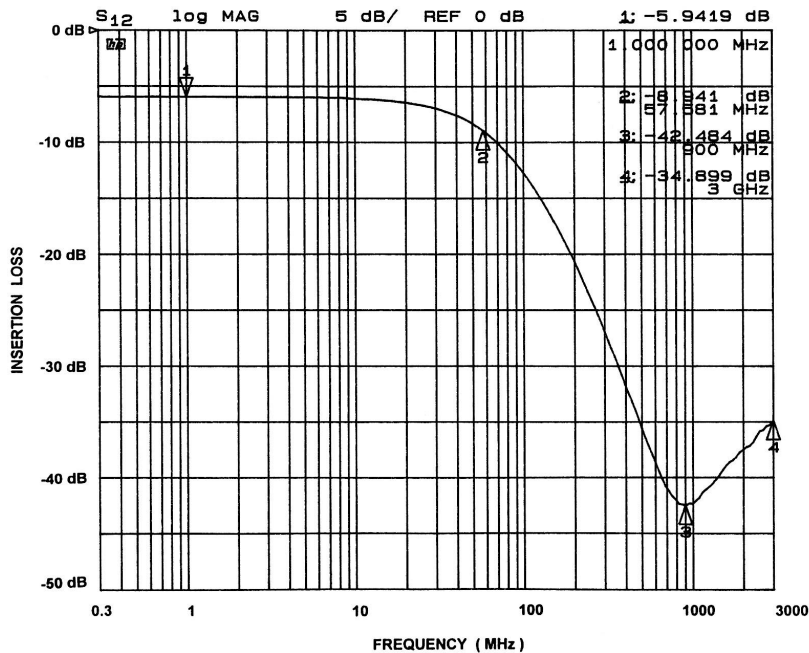
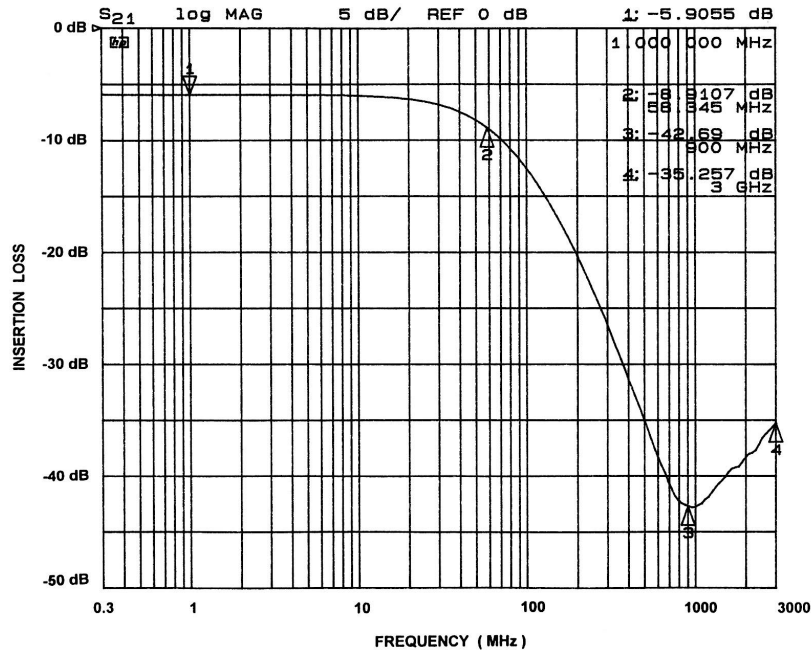


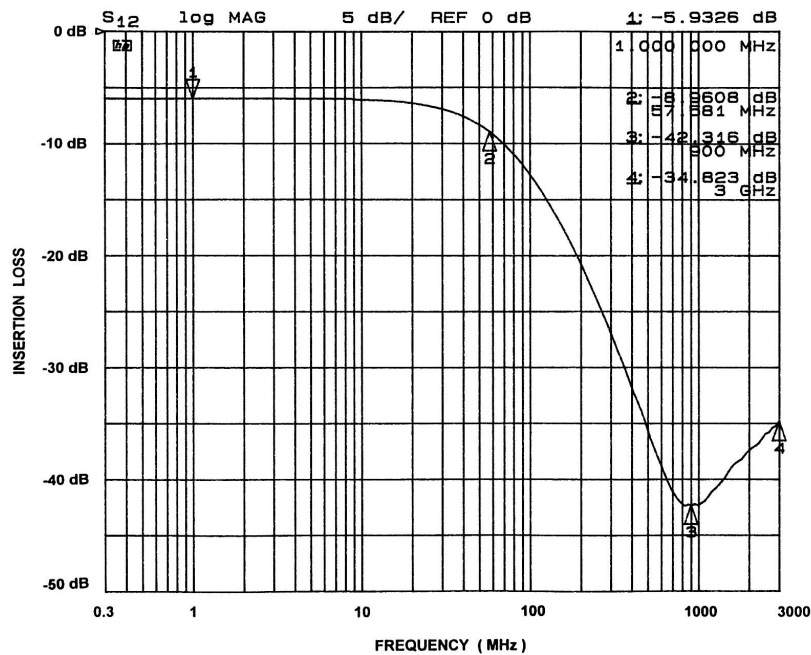
Figure 2. Insertion Loss VS. Frequency (A2-C2 to GND B2)

**Performance Information (cont'd)**

Typical Filter Performance ( $T_A=25^\circ\text{C}$ , DC Bias=0V, 50 Ohm Environment)



**Figure 3. Insertion Loss VS. Frequency (A3-C3 to GND B2)**



**Figure 4. Insertion Loss VS. Frequency (A4-C4 to GND B2)**



### Performance Information (cont'd)

Typical Filter Performance ( $T_A=25^\circ\text{C}$ , DC Bias=0V, 50 Ohm Environment)

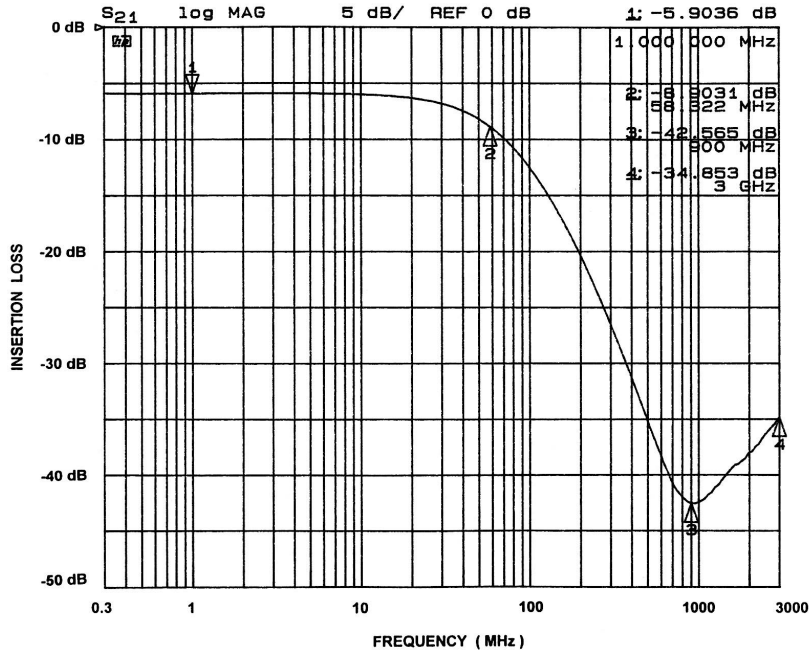


Figure 5. Insertion Loss VS. Frequency (A5-C5 to GND B2)

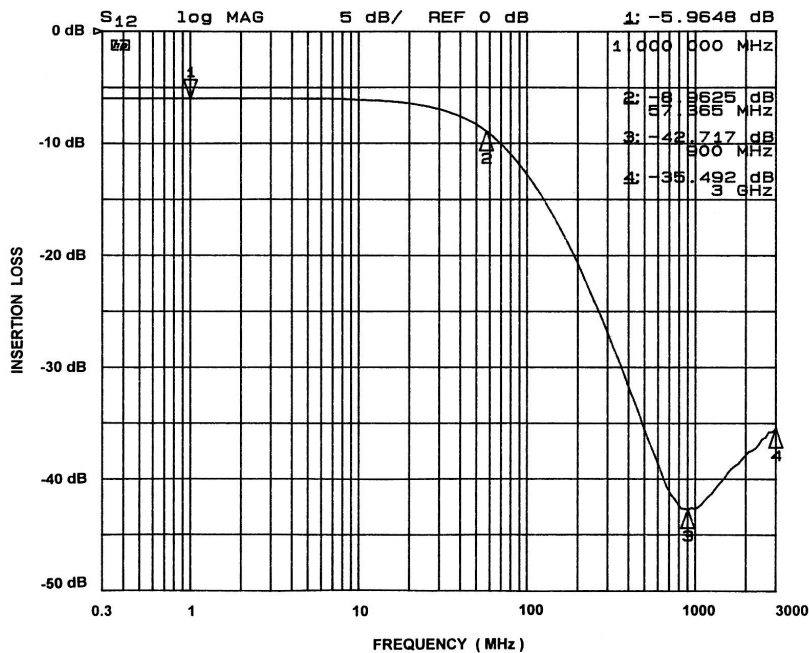


Figure 6. Insertion Loss VS. Frequency (A6-C6 to GND B2)



### Performance Information (cont'd)

Typical Filter Performance ( $T_A=25^\circ\text{C}$ , DC Bias=0V, 50 Ohm Environment)

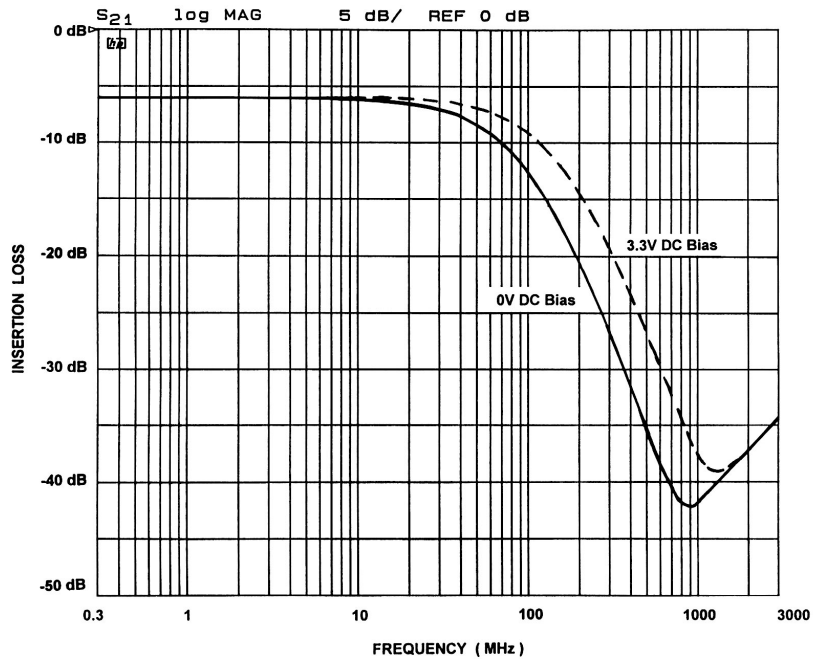
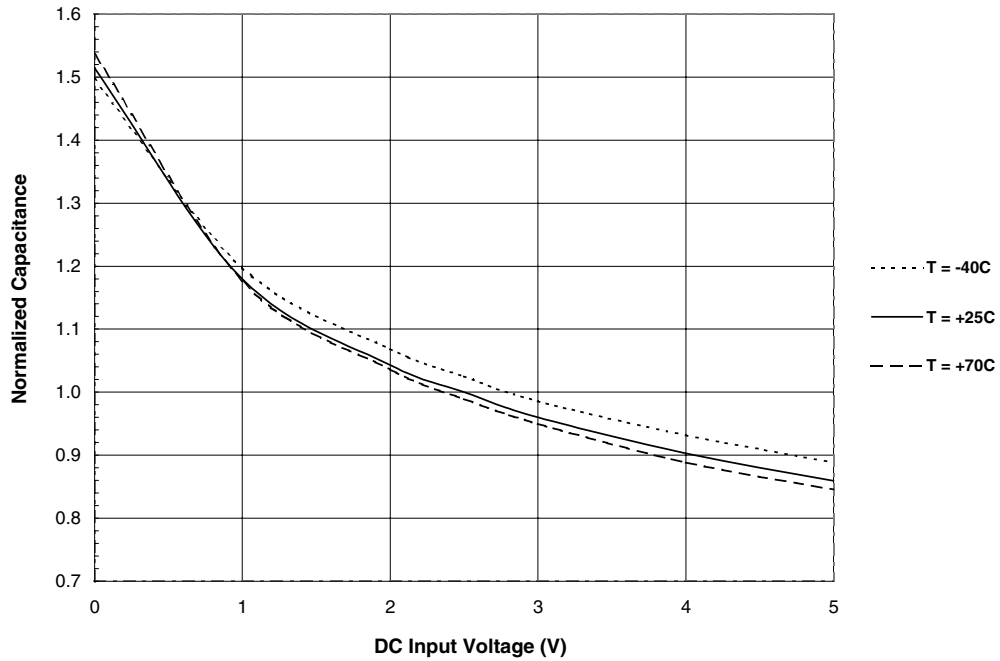


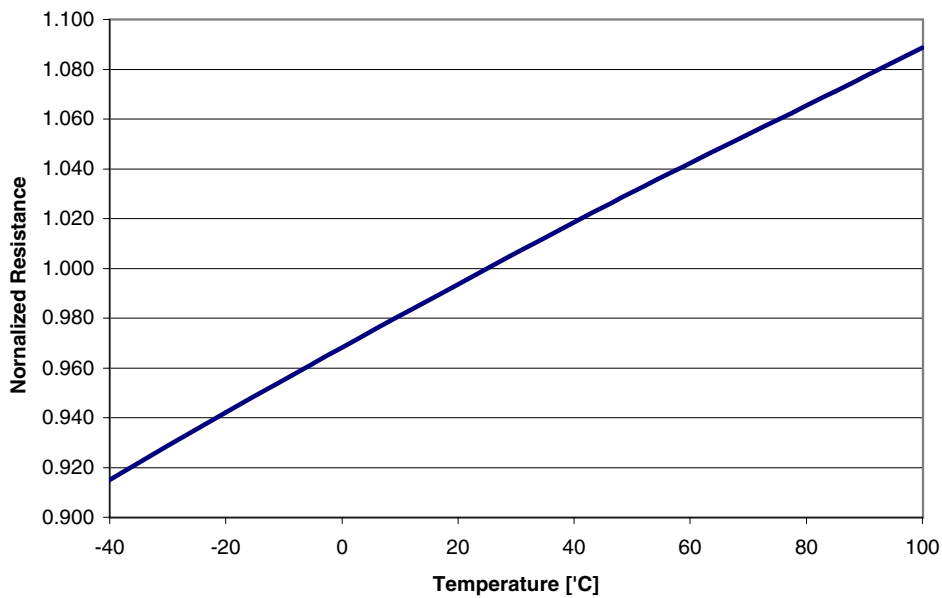
Figure 7. Comparison of Filter Response Curves for CSPEMI306A VS. DC Bias



### Performance Information (cont'd)



**Figure 8. Filter Capacitance vs. Input Voltage over Temperature (normalized to capacitance at 2.5VDC and 25°C)**



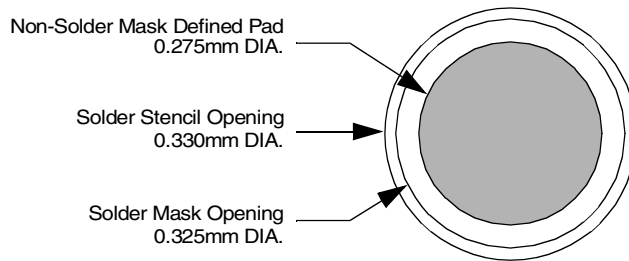
**Figure 9. Resistance vs. Temperature (normalized to resistance at 25°C)**



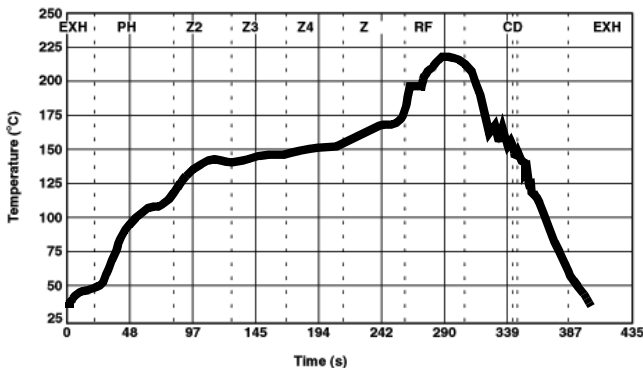
**Application Information**

Refer to Application Note AP-217, "The Chip Scale Package", for a detailed description of Chip Scale Packages offered by California Micro Devices.

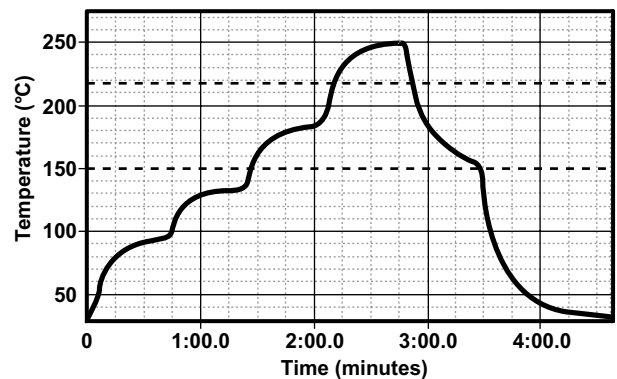
<b>PRINTED CIRCUIT BOARD RECOMMENDATIONS</b>	
<b>PARAMETER</b>	<b>VALUE</b>
Pad Size on PCB	0.275mm
Pad Shape	Round
Pad Definition	Non-Solder Mask defined pads
Solder Mask Opening	0.325mm Round
Solder Stencil Thickness	0.125 - 0.150mm
Solder Stencil Aperture Opening (laser cut, 5% tapered walls)	0.330mm Round
Solder Flux Ratio	50/50 by volume
Solder Paste Type	No Clean
Pad Protective Finish	OSP (Entek Cu Plus 106A)
Tolerance — Edge To Corner Ball	±50µm
Solder Ball Side Coplanarity	±20µm
Maximum Dwell Time Above Liquidous	60 seconds
Soldering Maximum Temperature	260°C



**Figure 10. Recommended Non-Solder Mask Defined Pad Illustration**



**Figure 11. Eutectic (SnPb) Solder Ball Reflow Profile**



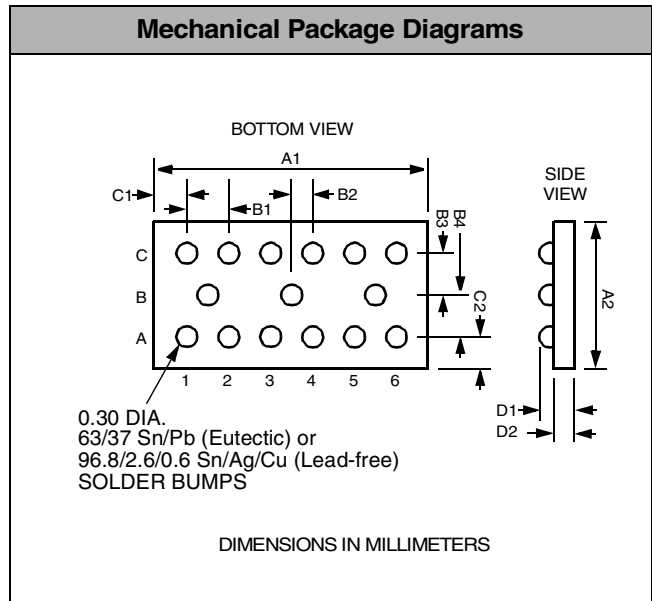
**Figure 12. Lead-free (SnAgCu) Solder Ball Reflow Profile**

**Mechanical Details**

**CSP Mechanical Specifications**

CSPEMI306A devices are packaged in a custom Chip Scale Package (CSP). Dimensions are presented below. For complete information on CSP packaging, see the California Micro Devices CSP Package Information document.

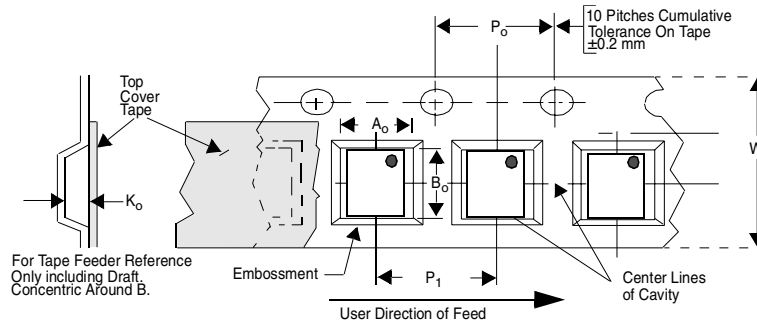
PACKAGE DIMENSIONS						
Package	Custom CSP					
Bumps	15					
Dim	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A1	2.915	2.960	3.005	0.1148	0.1165	0.1183
A2	1.285	1.330	1.375	0.0506	0.0524	0.0541
B1	0.495	0.500	0.505	0.0195	0.0197	0.0199
B2	0.245	0.250	0.255	0.0096	0.0098	0.0100
B3	0.430	0.435	0.440	0.0169	0.0171	0.0173
B4	0.430	0.435	0.440	0.0169	0.0171	0.0173
C1	0.180	0.230	0.280	0.0071	0.0091	0.0110
C2	0.180	0.230	0.280	0.0071	0.0091	0.0110
D1	0.561	0.605	0.649	0.0221	0.0238	0.0255
D2	0.355	0.380	0.405	0.0140	0.0150	0.0159
# per tape and reel	3500 pieces					
Controlling dimension: millimeters						



**Package Dimensions for CSPEMI306A Chip Scale Package**

**CSP Tape and Reel Specifications**

PART NUMBER	CHIP SIZE (mm)	POCKET SIZE (mm) B <sub>0</sub> X A <sub>0</sub> X K <sub>0</sub>	TAPE WIDTH W	REEL DIAMETER	QTY PER REEL	P <sub>0</sub>	P <sub>1</sub>
CSPEMI306A	2.96 X 1.33 X 0.6	3.10 X 1.45 X 0.74	8mm	178mm (7")	3500	4mm	4mm



**Figure 13. Tape and Reel Mechanical Data**